



BC857BFZ

45V PNP SMALL SIGNAL TRANSISTOR IN DFN0606

Features

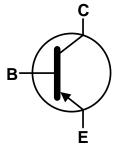
- $BV_{CEO} > -45V$
- I_C = -100mA High Collector Current
- P_D = 925mW Power Dissipation
- 0.36mm² Package Footprint, 40% Smaller than DFN1006
- 0.4mm Height Package Minimizing Off-Board Profile
- Complementary NPN Type BC847BFZ
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

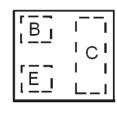
Mechanical Data

- Case: X2-DFN0606-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu, Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.0008 grams (Approximate)









Bottom View Top View

Device Symbol

Top View **Device Schematic**

Ordering Information (Note 4)

| Product | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-------------|---------|--------------------|-----------------|-------------------|
| BC857BFZ-7B | 3W | 7 | 8 | 10,000 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Top View Bar Denotes Base and Emitter Side

3W = Product Type Marking Code



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | -50 | V |
| Collector-Emitter Voltage | V _{CEO} | -45 | V |
| Emitter-Base Voltage | V _{EBO} | -6.0 | V |
| Continuous Collector Current | Ic | -100 | mA |
| Peak Pulse Collector Current | I _{CM} | -200 | mA |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | | |
|---|-----------------------------------|----------------|------|------|--|
| Power Dissipation | (Note 5) | D | 270 | mW | |
| Fower Dissipation | (Note 6) | P _D | 925 | | |
| Thermal Desistance, Junction to Ambient | (Note 5) | 465 | | °C/W | |
| Thermal Resistance, Junction to Ambient | (Note 6) | $R_{	hetaJA}$ | 135 | C/VV | |
| Thermal Resistance, Junction to Lead (Note 7) | | $R_{	heta JL}$ | 135 | °C/W | |
| Operating and Storage and Temperature Range | T _J , T _{STG} | -55 to +150 | °C | | |

ESD Ratings (Note 8)

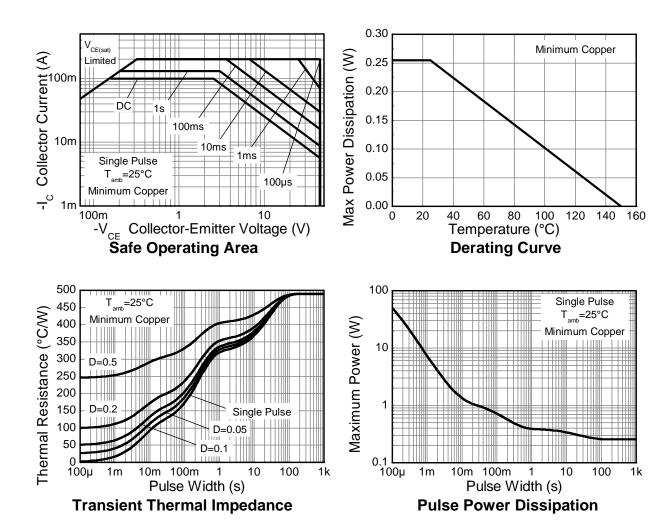
| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 200 | V | В |

Notes:

- For the device mounted on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady state condition. The entire exposed collector pad is attached to the heatsink.
 Same as Note 5, except the exposed collector pad is mounted on 25mm x 25mm 2oz copper.
 Thermal resistance from junction to solder-point (on the exposed collector pad).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





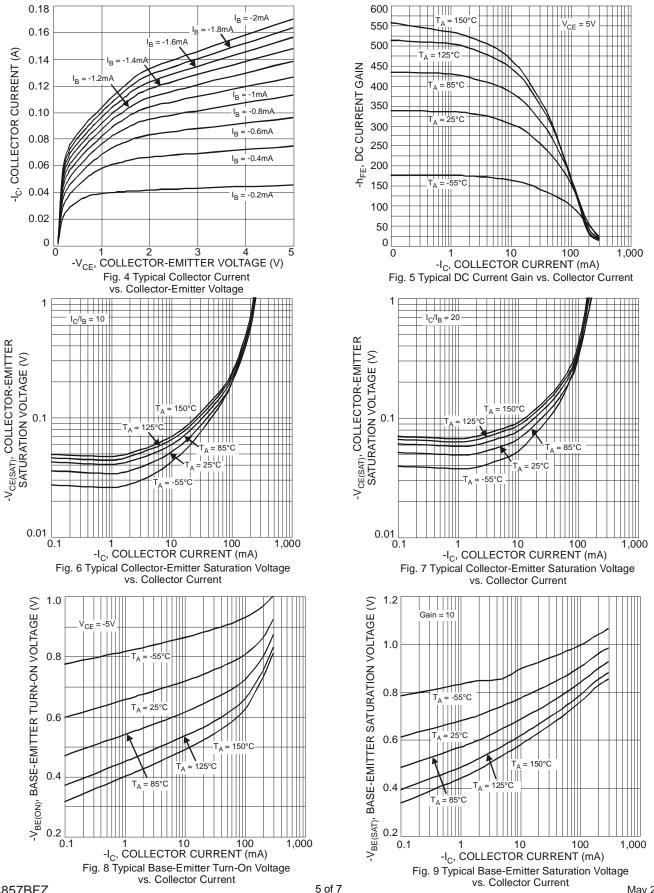
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typical | Max | Unit | Test Condition |
|--|----------------------|-----------|--------------|------------------|------|--|
| OFF CHARACTERISTICS | | | | | | |
| Collector-Base Breakdown Voltage | BV _{CBO} | -50 | -100 | _ | V | $I_C = -50\mu A, I_B = 0$ |
| Collector-Emitter Breakdown Voltage | BV _{CES} | -50 | -90 | _ | V | $I_C = -50\mu A, I_B = 0$ |
| Collector-Emitter Breakdown Voltage (Note 9) | BV _{CEO} | -45 | -65 | _ | V | $I_{C} = -1 \text{mA}, I_{B} = 0$ |
| Collector-Base Breakdown Voltage | BV _{EBO} | -6.0 | -8.5 | _ | V | $I_E = -50\mu A, I_C = 0$ |
| Collector-Base Cutoff Current | I _{CBO} | _ | _ | -15 | nA | V _{CB} = -40V |
| Collector-Emitter Cutoff Current | I _{CES} | _ | _ | -15 | nA | V _{CE} = -40V |
| ON CHARACTERISTICS (Note 9) | | | | | | |
| DC Current Gain | h _{FE} | _ 200 | 340 330 | — 470 | - | $I_C = -10\mu A$, $V_{CE} = -5.0V$ $I_C = -2.0mA$, $V_{CE} = -5.0V$ |
| Collector-Emitter Saturation Voltage | V _{CE(sat)} | _ | -70 -300 | -175 -500 | mV | $I_C = -10$ mA, $I_B = -0.5$ mA $I_C = -100$ mA, $I_B = -5.0$ mA |
| Base-Emitter Saturation Voltage | V _{BE(sat)} | _ | -760 -885 | -1,000 -1,100 | mV | $I_C = -10$ mA, $I_B = -0.5$ mA $I_C = -100$ mA, $I_B = -5.0$ mA |
| Base-Emitter Voltage | V _{BE(on)} | -600 — | -670 -715 | -780 -850 | mV | $I_C = -2.0$ mA, $V_{CE} = -5$ V $I_C = -10$ mA, $V_{CE} = -5$ V |
| SMALL SIGNAL CHARACTERISTICS | | | | | | |
| Output Capacitance | C _{obo} | _ | 2.0 | _ | pF | $V_{CB} = -10.0V$, $f = 1.0MHz$, $I_E = 0$ |
| Current Gain-Bandwidth Product | f⊤ | 100 | 270 | _ | MHz | V _{CE} = -5V, I _C = -10mA, f = 100MHz |

Note: 9. Measured under pulsed conditions. Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2\%$.



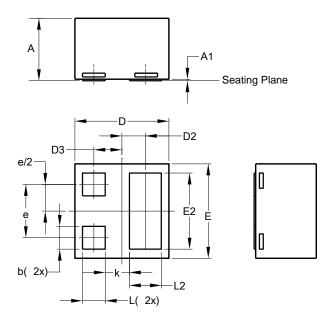
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





Package Outline Dimensions

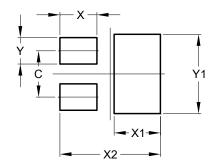
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



| X2-DFN0606-3 | | | | | |
|----------------------|-----------|---------|------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 0.36 | 0.42 | 0.39 | | |
| A1 | 0 | 0.05 | 0.02 | | |
| b | 0.10 | 0.20 | 0.15 | | |
| D | 0.57 | 0.67 | 0.62 | | |
| D2 | 0.155 BSC | | | | |
| D3 | 0 | .185 BS | C | | |
| Е | 0.57 | 0.67 | 0.62 | | |
| E2 | 0.40 | 0.60 | 0.50 | | |
| е | 0.35 BSC | | | | |
| k | 0.16 REF | | | | |
| L | 0.09 | 0.21 | 0.15 | | |
| L2 | 0.11 | 0.31 | 0.21 | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 0.350 |
| Х | 0.280 |
| X1 | 0.350 |
| X2 | 0.760 |
| Υ | 0.200 |
| V1 | 0.600 |



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